Rochester Electronics

Datasheet

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
    - Class Q Military
    - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)

    - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

FAIRCHILD SEMICONDUCTOR®

June 1993
Revised April 2005

74LVX573
Low Voltage Octal Latch with 3-STATE Outputs

General Description

The LVX573 is a high-speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ($\overline{OE}$) inputs. The LVX573 is functionally identical to the LVX373 but with inputs and outputs on opposite sides of the package. The inputs tolerate up to 7V allowing interface of 5V systems to 3V systems.

Features

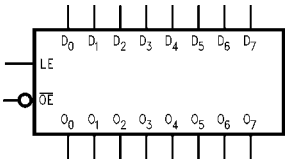
- Input voltage translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

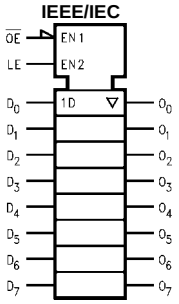
Order Number	Package Number	Package Description
74LVX573M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVX573SJ	M20D	Pb-Free 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX573MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.
Pb-Free package per JEDEC J-STD-020B.

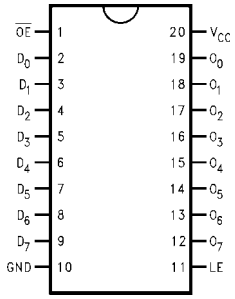
Logic Symbols



IEEE/IEC



Connection Diagram



Pin Descriptions

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Latch Outputs

Functional Description

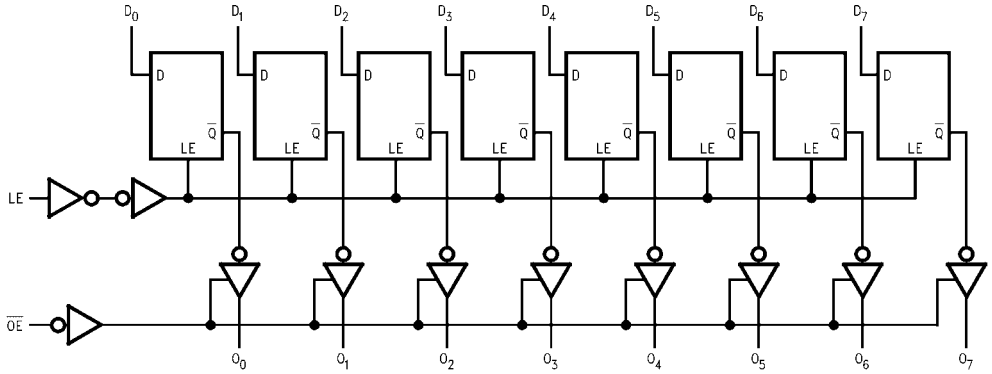
The LVX573 contains eight D-type latches. When the enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are enabled. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
$\overline{OE}$	LE	D	O_n
L	H	H	H
L	H	L	L
L	L	X	O_0
H	X	X	Z

H = HIGH Voltage
L = LOW Voltage
Z = High Impedance
X = Immaterial
O_0 = Previous O_0 before HIGH-to-LOW transition of Latch Enable

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
DC Input Voltage (V_I)	−0.5V to 7V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±25 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±75 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Input Rise and Fall Time ($\Delta t/\Delta V$)	0 ns/V to 100 ns/V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	T_A = +25°C			T_A = −40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{IH}	HIGH Level Input Voltage	2.0	1.5			1.5				
		3.0	2.0			2.0		V		
		3.6	2.4			2.4				
V_{IL}	LOW Level Input Voltage	2.0			0.5		0.5			
		3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V_{OH}	HIGH Level Output Voltage	2.0	1.9	2.0		1.9			V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA
		3.0	2.9	3.0		2.9		V		I_{OH} = −50 μA
		3.0	2.58			2.48				I_{OH} = −4 mA
V_{OL}	LOW Level Output Voltage	2.0		0.0	0.1		0.1		V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA
		3.0		0.0	0.1		0.1	V		I_{OL} = 50 μA
		3.0			0.36		0.44			I_{OL} = 4 mA
I_{OZ}	3-STATE Output Off-State Current	3.6			±0.25		±2.5	μA	V_{IN} = V_{IH} or V_{IL}; V_{OUT} = V_{CC} or GND	
I_{IN}	Input Leakage Current	3.6			±0.1		±1.0	μA	V_{IN} = 5.5V or GND	
I_{CC}	Quiescent Supply Current	3.6			4.0		40.0	μA	V_{IN} = V_{CC} or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V_{CC} (V)	T_A = 25°C		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.5	0.8	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.5	−0.8	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 3: (Input t_r = t_f = 3ns)

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units	Conditions
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation	2.7		7.6	14.5	1.0	17.5	ns	$C_L = 15$ pF
t_{PHL}	Delay Time			10.1	18.0	1.0	21.0		$C_L = 50$ pF
	D_n to O_n	3.3 ± 0.3		5.9	9.3	1.0	11.0		$C_L = 15$ pF
				8.4	12.8	1.0	14.5		$C_L = 50$ pF
t_{PLH}	Propagation	2.7		8.2	15.6	1.0	18.5	ns	$C_L = 15$ pF
t_{PHL}	Delay Time			10.7	19.1	1.0	22.0		$C_L = 50$ pF
	LE to O_n	3.3 ± 0.3		6.4	10.1	1.0	12.0		$C_L = 15$ pF
				8.9	13.6	1.0	15.5		$C_L = 50$ pF
t_{PZL}	3-STATE Output	2.7		7.8	15.0	1.0	18.5	ns	$C_L = 15$ pF, $R_L = 1$ kΩ
t_{PZH}	Enable Time			10.3	18.5	1.0	22.0		$C_L = 50$ pF, $R_L = 1$ kΩ
		3.3 ± 0.3		6.1	9.7	1.0	12.0		$C_L = 15$ pF, $R_L = 1$ kΩ
				8.6	13.2	1.0	15.5		$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PLZ}	3-STATE Output	2.7		12.1	19.1	1.0	22.0	ns	$C_L = 50$ pF, $R_L = 1$ kΩ
t_{PHZ}	Disable Time	3.3 ± 0.3		10.1	13.6	1.0	15.5		$C_L = 50$ pF, $R_L = 1$ kΩ
t_W	LE Pulse	2.7	6.5			7.5		ns	
	Width	3.3 ± 0.3	5.0			5.0			
t_S	Setup Time	2.7	5.0			5.0		ns	
	D_n to LE	3.3 ± 0.3	3.5			3.5			
t_H	Hold Time	2.7	1.5			1.5		ns	
	D_n to LE	3.3 ± 0.3	1.5			1.5			
t_{OSHL}	Output to Output	2.7			1.5		1.5	ns	$C_L = 50$ pF
t_{OSLH}	Skew (Note 4)	2.3			1.5		1.5		

Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$.

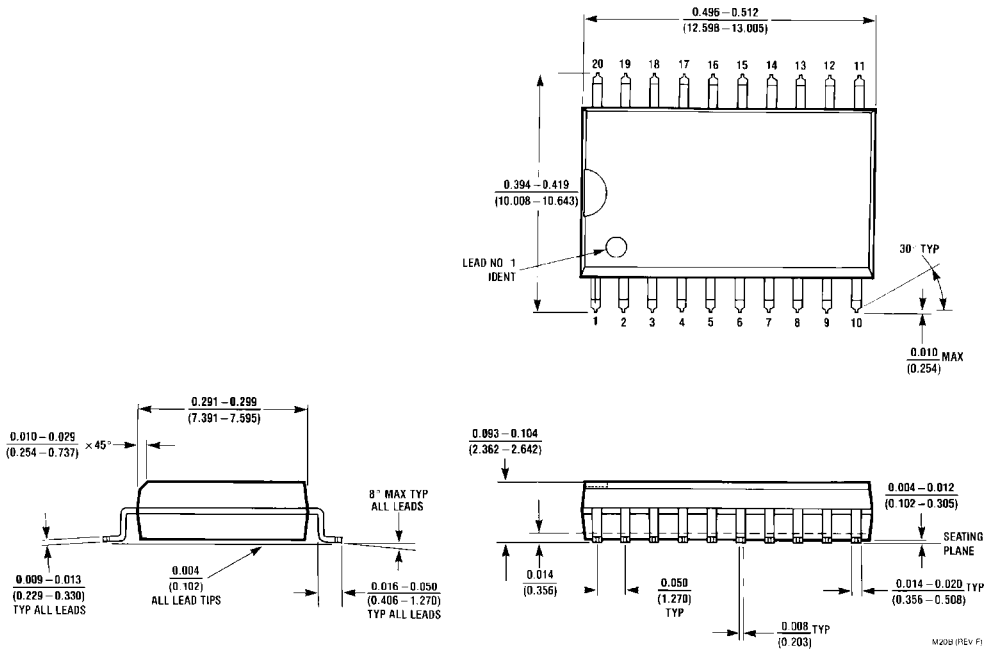
Capacitance

Symbol	Parameter	$T_A = +25°C$			$T_A = -40°C$ to $+85°C$		Units
		Min	Typ	Max	Min	Max	
C_{IN}	Input Capacitance		4	10		10	pF
C_{OUT}	Output Capacitance		6				pF
C_{PD}	Power Dissipation Capacitance (Note 5)		27				pF

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

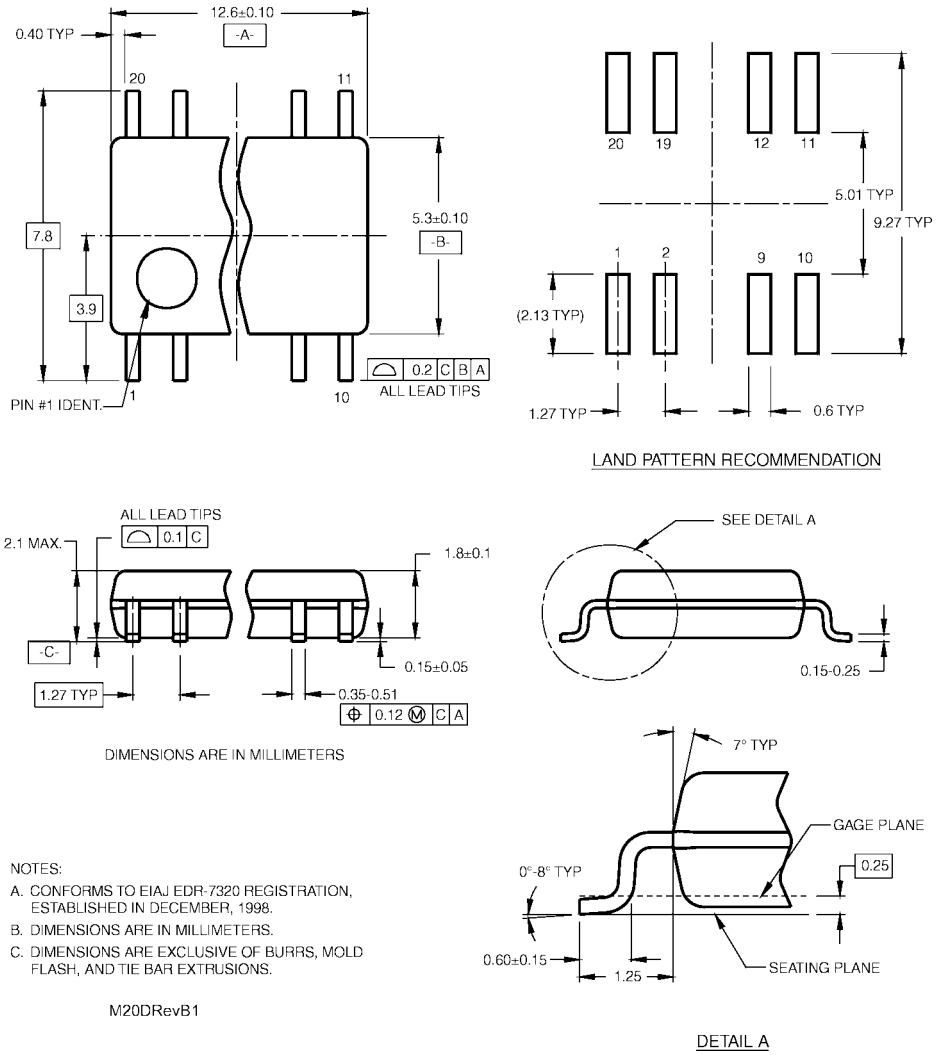
Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{8 \text{ (per latch)}}$

Physical Dimensions inches (millimeters) unless otherwise noted



20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.

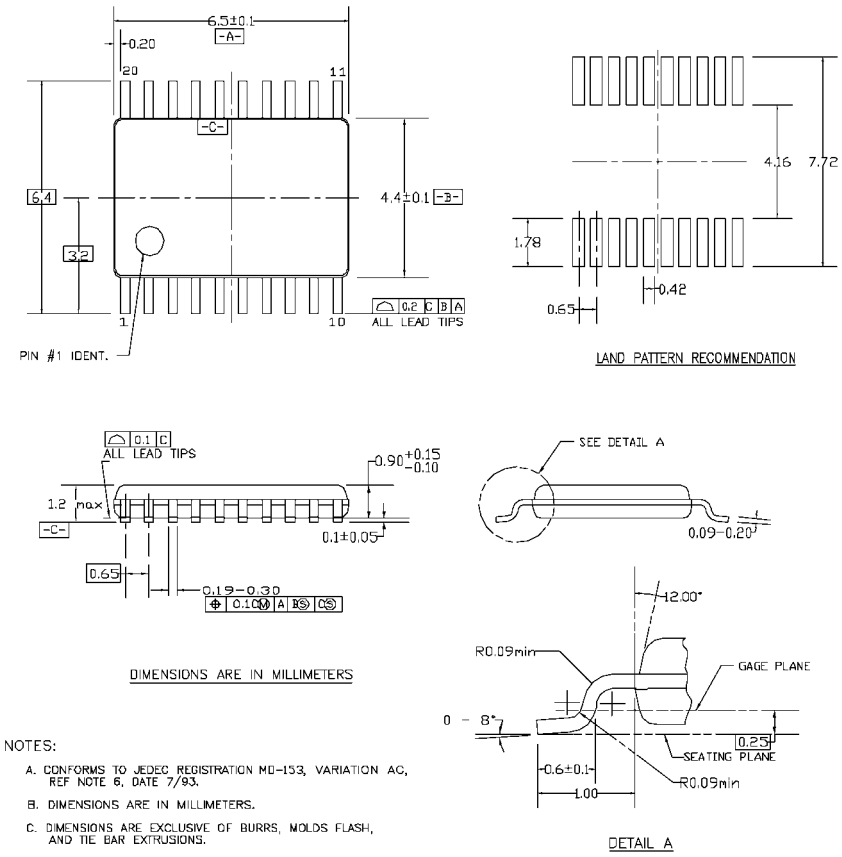
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M20DRevB1

Pb-Free 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AC, REF NOTE 6, DATE 7/93.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC20REVD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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